

ПРИЕМНИКИ ИНФРАКРАСНОГО И ТЕРАГЕРЦОВОГО ИЗЛУЧЕНИЯ НА ОСНОВЕ ТОНКОПЛЕНОЧНЫХ СВЕРХПРОВОДНИКОВЫХ НАНОСТРУКТУР



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План

•Ультратонкая сверхпроводниковая NbN пленка как уникальный материал для сверхчувствительных терагерцовых и инфракрасных детекторов.

•Сверхпроводниковый болометр на горячих электронах (НЕВ) и его применения в терагерцовой радиоастрономии.

•Сверхпроводниковый болометр на горячих электронах (HEB) как прямой детектор; •Сверхпроводниковый однофотонный детектор (SSPD) в инфракрасном и терагерцовом диапазонах.

- Однофотонный нановолноводный детектор для интегральной оптики.
- SSPD как однофотонный смеситель для гетеродинной спектроскопии.

•Заключение

Ultrathin superconducting NbN film structure

NbN on 3C-SiC buffer layer on Si substrate (HREM)



Glue NbN is monocrystalline $a_0 (3C-SiC) = 4.36 \text{\AA}$ $a_0 (NbN) = 4.39 \text{\AA}$ Thickness is 3.5 - 4.1 nmNot really flat surface

NbN on Si substrate



The NbN on Si is polycrystalline.

J.-R. Gao, G. Gol'tsman, B. Voronov, et al, APL (2007)

SEM micrographs of the central area of HEB mixer chip



Our NbN films are space-qualified



Herschel Space Observatory launched, May 2009 HEB mixers in Bands 6 and 7 of the HIFI instrument: 1.41 THz – 1.91 THz



HIFI Spectrum of Water and Organics in the Orion Nebula

© ESA, HEXOS and the HIFI consortium E. Bergin

HEB mixers in radio astronomy: now and future

HERSCHEL

Launched in 2009.3.5-m diameter space telescope.HEB for 1.41–1.91 THz



Millimetron

10-m diameter space telescope HEB for 1-6THz heterodyne receiver



The GBW of the HEB-based HIFI receiver does not exceed 4 GHz.

Need more for future heterodyne missions – 8 GHz and more.



From waveguide mixer chip to practical receiver up to 1.5 THz and astronomical observations in



Chile from an altitude of 5525 meters

Superconducting waveguide hotelectron bolometer (HEB) mixer at 1.5 THz frequency



The 1.5 THz chip's sizes are 72 um wide, 1100 um long and 18 um thick



The Receiver Lab Telescope of the Harvard-Smithsonian Center for Astrophysics is the first ground-based radio telescope designed for operation at frequencies above 1 THz.

Observations since 2002 from an altitude of 5525 meters in Chile at 0.8-1.5 THz

HEB Mixers on SOI wafers for Greenland Telescope

- The Greenland Telescope is based on the ALMA North America prototype antenna built by Vertex AG, which will be refitted for operation in the colder and somewhat lower altitude conditions.
- It is a 12-m diameter Cassegrain system with a primary F/d ratio of 0.4 and maximum field of view of approximately 15 arc-min



The Greenland Telescope antenna in its current location at the VLA site in Socorro, NM



The Greenland Telescope will be deployed at Apex Station, a new NSF operated Arctic research station to be constructed 5 miles north of the existing Summit Station at 72°35'N 38°25'W and 3,210 m (10,530 ft) above mean sea level.

The site is near the peak of the Greenland ice sheet, near the center of Greenland.

Location of Summit/Apex Stations in Greenland

http://www.cfa.harvard.edu/greenland12m/

HEB Mixers on SOI wafers for Greenland Telescope

Frequency (GHz)	Wavelength (mm)	Receiver Noise (K)	Transmission	System Noise (K)	Continuum NEFD (mJy/beam 1s)	Spectral NEFD (mJy/beam 1s, 1km/s)	Spectral NEFD (K/beam 1s, 1km/s)
1050	0.286	525	0.16	7798	3748.2	179199.0	4.17
1300	0.231	650	0.16	10659	5942.8	255344.1	5.12
1500	0.200	750	0.15	14711	9448.9	377955.2	6.58



Calculated atmospheric transmission at Apex Station for median (red) and 10% (blue) winter (Oct-May) conditions

http://www.cfa.harvard.edu/greenland12m/

HEB Mixers for Greenland Telescope: test deep etching of Si



SEM photograph of the Si etched surface



Image of the membrane with an optical microscope. (The membrane is transparent to light)

Hot electron bolometers as direct detectors

are capable to detect aJ pulse energy at GHz rate



NEP ≈ 3×10⁻¹³ *W*/√*Hz*



Double dipole antenna coupled bolometer

$W_{pulse} = SNR \times NEP \times \sqrt{\tau_{bol}} \approx 10 aJ < SNR^2 \times hv \approx 25 aJ$

No photon shot noise in THz!



Signal to noise ratio (SNR) \approx 5 is required for stable link

New Horizons:

approaching Pluto (artist's view, to happen in summer 2015)

2.1 m diameter dish antenna to communicate with Earth from 7.5 billion kilometers away

Credit: Johns Hopkins University Applied Physics Laboratory/Southwest Research Institute (JHUAPL/SwRI)

Experimental set-up: short THz pulses and HEB detector with record energy resolution



First observation of SSPD response and first idea of device physics



Distance, rel. units

PHYSICA G

www.elsevier.nl/locate/nhvs

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Fig. 1. Concentration of nonequilibrium quasiparticles across the width of the film at different moments after the photon has been absorbed. Time delays are 0.8, 2.0 and 5.0 measured in units of the thermalization time. Distance from the absorption site is shown in units of the thermalization length. Inset illustrates redistribution of supercurrent in the superconducting film with the normal spot - the basis of quantum detection. It shows the cross-section of the film drawn through the point where photon has been absorbed.

FIG. 1. Schematics of the supercurrent-assisted hotspot formation mechanism in an ultrathin and narrow superconducting strip, kept at temperature far below T_{C} are shown. The arrows indicate direction of the supercurrent flow.

Meander-type SSPD Fabrication

Fabrication:

- DC magnetron sputtering of NbN film on sapphire (Al₂O₃) substrate
- E-beam lithography with reactive ion etching

Present day challenges:

- increase filling factor (presently about 60%)
- to reduce strip width from 100 nm to 50 nm or even less



Korneev A. et al, Appl. Phys. Lett. 84 (2004) 5338

2 Mm

First Implementation of NbN SSPD: Silicon CMOS IC Device Debug OptiCA[®] System with NbN SSPD commercialized by NPTest, Inc.



For more information:

http://www.nptest.com/products/probe/idsOptica.htm

Practical detectors and systems





Two-channel single-photon receiver

Cryocooler-based solution



Practical single-photon receiver based on SSPD

Now: Quantum efficiency 80% at 1550nm, jitter 20ps, max. counting rate 100 MHz and dark count rate 10s⁻¹





Cavity-integrated SSPD



Spectral range	Quantum efficiency (referred to optical input)			
0.7 – 1.3 μm	85 %			
1.3 – 1.6 μm	80 %			
1.6 – 2.3 μm	50 %			



High Speed Travelling Wave Single-Photon Detectors With Near-Unity Quantum Efficiency W. Pernice, C. Schuck, O. Minaeva, M. Li, G. Goltsman, A. Sergienko, H. Tang, "High speed travelling wave single-photon detectors with near-unity quantum efficiency", Nature Communications, 3, 1325 (2012)



a) Principle of the travelling wave SSPD: a sub-wavelength absorbing NbN nanowire is patterned atop a silicon waveguide to detect single photons; Max. QE=91%

b) Optical micrograph of a fabricated device showing the optical input circuitry, RF contact pads and the SSPD; Inset: zoom into the detector region with an SEM image showing the detector regime. The control and residual ports are used for calibration purposes.

Single-photon platform for the realization of integrated quantum optics.



Why silicon nitride?

- Wide band gap \rightarrow small absorption in visible and in IR range

- High refractive index Good mechanical properties Possibility to create SPS due to nonlinearity Compatibility with NbN thin film deposition process

Why on-chip photonics?

- ✓ The ability to integrate a huge number of optical components in a small area,
 ✓ Superposition of quantum states can be easily
- represented, encrypted, transmitted and detected
- ✓ Easy to manipulate (Linear **Optics Quantum** computation(LOQC), using only linear optical elements: beam splitters, phase shifters and mirrors)
- \checkmark Low power consumption

Why WSSPD?

- Compact design
 High detection
- efficiency ✓ Low timing jitter ✓ Low dead time
- ✓ No gating needed
 ✓ No afterpulsing

SEM image of a fabricated nanophotonic circuits

SEM image of a fabricated nanophotonic circuit for balance measurements of an absorption coefficient



False colors of nanowire atop of waveguide with different width



On-chip detection efficiency (OCDE)

SEM Image of a U-shaped nanowire OCDE vs NbN nanowire width (U-shaped



SEM Image of a W-shaped nanowire OCDE vs NbN nanowire width (W-shaped)



The best W-shaped nanowire



MZI with two directional couplers

Optical image of MZI with two directional couplers

SEM image of the directional coupler



SSPD as a photon counting mixer for heterodyne spectroscopy: Operation principle:



SSPD as a photon counting mixer for heterodyne spectroscopy: Measurement setup:



Amplified pulses from SSPD



Professor Gregory Goltsman received the IEEE Award for Continuing and Significant Contributions to Applied Superconductivity at the International Superconductive Electronics Conference in Sorrento, Italy, 13 June 2017.



http://ieeecsc.org/news/professor-gregory-goltsman-received-ieee-award-continuing-and-significant-contributions-applied

Thank you for your attention!

Laboratory prototype of .hertz imager





HEB mixer integrated with FFO local oscillator







